

# **BYW81HR**

## Aerospace 1 x 15 A - 200 V fast recovery rectifier

#### **Datasheet - production data**



### **Features**

- Very small conduction losses .
- Negligible switching losses •
- High surge current capability .
- High avalanche energy capability .
- Hermetic packages
- ESCC qualified •

### Description

Packaged in hermetic SMD.5, this device is intended for use in medium voltage, high frequency switching mode power supplies, high frequency DC to DC converters, and other aerospace applications.

The complete ESCC specification for this device is available from the European Space Agency web site. ST guarantees full compliance of qualified parts with such ESCC detailed specifications.

### Figure 1. Device configuration



### Table 1. Device summary<sup>(1)</sup>

| Order code  | ESCC part<br>number | Quality<br>level     | EPPL | Package | I <sub>F(AV)</sub> | V <sub>RRM</sub> | V <sub>F (max)</sub> | T <sub>j(max)</sub> |
|-------------|---------------------|----------------------|------|---------|--------------------|------------------|----------------------|---------------------|
| BYW81-200S1 |                     | Engineering<br>model |      | SMD.5   | 15 A               | 200 V            | 1.15 V               | 150 °C              |
| BYW81-200SG | 5103/029/05         | ESCC flight          | Y    | SMD.5   | 15 A               |                  |                      |                     |

1. Contact ST sales office for information about the specific conditions for products in die form.

## 1 Characteristics

| Symbol              | Characteristic  | Value       | Unit |
|---------------------|---|-------------|------|
| I <sub>FSM</sub>    | Forward surge current <sup>(1)</sup> , variant 05                             | 250         | А    |
| V <sub>RRM</sub>    | Repetitive peak reverse voltage <sup>(2)</sup>                                | 200         | V    |
| Ι <sub>ο</sub>      | Average output rectified current (50% duty cycle) <sup>(3)</sup> , variant 05 | 15          | A    |
| I <sub>F(RMS)</sub> | Forward rms current (per diode), variant 05                                   | 30          | A    |
| T <sub>OP</sub>     | Operating case temperature range  | -55 to +150 | °C   |
| $T_{J}$             | Junction temperature  | +150        | °C   |
| T <sub>STG</sub>    | Storage temperature range   | -55 to +150 | °C   |
| T <sub>SOL</sub>    | Soldering temperature SMD.5 <sup>(4)</sup>                                    | +245        | °C   |

#### Table 2. Absolute maximum ratings

1. Sinusoidal pulse of 10 ms duration

2. Pulsed, duration 5 ms, F = 50 Hz

3. For  $T_{case} \ge +110^{\circ}$ C, derate linearly to 0 A at +150°C.

4. Duration 5 seconds maximum the same package shall not be re-soldered until 3 minutes have elapsed.

#### Table 3. Thermal resistance

| Symbol                               | Parameter                                  | Value | Unit |
|--------------------------------------|--|-------|------|
| R <sub>th (j-c)</sub> <sup>(1)</sup> | Junction to case, all variants (per diode) | 2.3   | °C/W |

1. Package mounted on infinite heatsink.



| Symbol                              | Characteristic                               | MIL-STD-750<br>test method | Test conditions   | Lin        | Units                     |       |
|-------------------------------------|--|----------------------------|---|------------|---------------------------|-------|
|                                     | Characteristic                               |                            | lest conditions   | Min.       | Max.                      | Units |
| I <sub>R</sub>                      | Reverse current                              | 4016                       | DC method, $V_R = 200 V$  | -          | 20                        | μA    |
| $V_{F1}^{(1)}$                      | Forward voltage                              | 4011                       | Pulse method, I <sub>F</sub> = 10 A   | -          | 1.0                       | V     |
| $V_{F2}^{(1)}$                      | Forward voltage                              | 4011                       | Pulse method, I <sub>F</sub> = 20 A   | -          | 1.2                       | V     |
| $V_{BR}$                            | Breakdown voltage                            | 4021                       | I <sub>R</sub> = 100 μA   | 200        | -                         | V     |
| С                                   | Capacitance                                  | 4001                       | V <sub>R</sub> = 10 V, F = 1 MHz  | -          | 220                       | pF    |
| t <sub>rr</sub>                     | Reverse recovery time                        | 4031                       | I <sub>F</sub> = 1 A, V <sub>R</sub> = 30 V,<br>dI <sub>F</sub> /dt = -50 A/μs                                    | -          | 40                        | ns    |
| Z <sub>th(j-c)</sub> <sup>(2)</sup> | Relative thermal impedance, junction to case | 3101                       | $I_{H} = 15 \text{ to } 40 \text{ A}, t_{H} = 50 \text{ ms}$<br>$I_{M} = 50 \text{ mA}, t_{md} = 100 \mu\text{s}$ | Calc<br>∆V | ulate<br>F <sup>(3)</sup> | °C/W  |

1. Pulse width  $\leq$  680µs, duty cycle  $\leq$  2%

2. Performed only during screening tests parameter drift values (initial measurements), go-no-go.

3. The limits for  $\Delta VF$  shall be defined by the manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the  $R_{th(j-c)}$  limits specified in maximum ratings.

### Table 5. Electrical measurements at high and low temperatures (per diode)

| Symbol         | Characteristic                                 | MIL-STD-750 | Test conditions <sup>(1)</sup>  | Limits |      | Units |
|----------------|--|-------------|---|--------|------|-------|
| Symbol         | test meth                                      |             |   | Min.   | Max. |       |
| I <sub>R</sub> | Reverse current                                | 4016        | T <sub>case</sub> = +125 (+0, -5) °C<br>DC method, V <sub>R</sub> = 200 V   | -      | 10   | mA    |
| V (2)          | Forward voltage                                | 4011        | T <sub>case</sub> = +125 (+0, -5) °C<br>pulse method, I <sub>F</sub> = 10 A | -      | 0.85 | V     |
| V F1           | V <sub>F1</sub> <sup>(2)</sup> Forward voltage |             | $T_{case} = +55 (+0, -5) °C$<br>pulse method, I <sub>F</sub> = 10 A         | -      | 1.15 | V     |

1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.

2. Pulse width  $\leq$  300µs, duty cycle  $\leq$  2%



## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

### 2.1 SMD.5 package information





### Table 6. SMD.5 package mechanical data

| Reference         | Dimension in | n millimeters | Dimension in inches |       |  |
|-------------------|--------------|---------------|---------------------|-------|--|
| Reference         | Min.         | Max.          | Min.                | Max.  |  |
| A                 | 2.84         | 3.15          | 0.112               | 0.124 |  |
| A1                | 0.25         | 0.51          | 0.010               | 0.20  |  |
| b                 | 7.13         | 7.39          | 0.281               | 0.291 |  |
| b1                | 5.58         | 5.84          | 0.220               | 0.230 |  |
| b2 <sup>(1)</sup> | 2.28         | 2.54          | 0.090               | 0.100 |  |
| b3 <sup>(1)</sup> | 2.92         | 3.18          | 0.115               | 0.125 |  |
| D                 | 10.03        | 10.28         | 0.395               | 0.405 |  |
| D1 <sup>(1)</sup> | 0.76         | -             | 0.030               | -     |  |
| E                 | 7.39         | 7.64          | 0.291               | 0.301 |  |
| e <sup>(1)</sup>  | 1.91         | BSC           | 0.0                 | )75   |  |

1. 2 locations





## **3** Ordering information

|             | 1                   |                      |         |                |                        |       |               |
|-------------|---------------------|----------------------|---------|----------------|------------------------|-------|---------------|
| Order code  | ESCC part<br>number | Quality<br>level     | Package | Lead<br>finish | Marking <sup>(2)</sup> | Mass  | Packing       |
| BYW81-200S1 |                     | Engineering<br>model | SMD.5   | Gold           | BYW81-200S1            | 2.0 g | Strip<br>pack |
| BYW81-200SG | 5103/029/05         | ESCC flight          |         |                | 510302905              |       | μασκ          |

| Table 7. Ordering information 7 | ing information | n(1) |
|---------------------------------|-----------------|------|
|---------------------------------|-----------------|------|

1. Contact ST sales office for information about the specific conditions for products in die form.

2. Specific marking only. The full marking includes in addition:

For the engineering models: ST logo, date code, country of origin (FR).

For ESCC flight parts: ST logo, date code, country of origin (FR), ESA logo, serial number of the part within the assembly lot.

## 4 Other information

### 4.1 Date code

Date code is structured as describe below:

- EM xyywwz
- ESCC flight yywwz

Where:

- x (EM only): 3, assembly location Rennes (France)
- yy: last two digits year
- ww: week digits
- z: lot index in the week

### 4.2 Documentation

In Table 8 is a summary of the documentation provided with each type of products.

| Quality level     | Documentation              |
|-------------------|----------------------------|
| Engineering model |                            |
| ESCC flight       | Certificate of conformance |



## 5 Revision history

| Date        | Revision | Changes  |
|-------------|----------|--|
| 3-Nov-2010  | 1        | First issue.   |
| 8-Nov-2013  | 2        | Inserted Ordering information.   |
| 10-Sep-2015 | 3        | Updated <i>Features</i> .<br>Removed TO-254 package and information and reformatted to<br>current standards. |

#### Table 9. Document revision history



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